# EMH4 / UMH4N / IMH4A

NPN 100mA 50V Complex Digital Transistors (Bias Resistor Built-in Transistors)

Datasheet

Parameter	Tr1 and Tr2
$V_{CEO}$	50V
I <sub>C(MAX.)</sub>	100mA
$R_1$	10kΩ

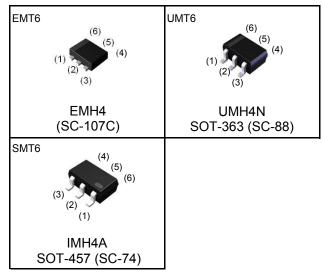
### Features

- 1) Built-In Biasing Resistors.
- 2) Two DTC114T chips in one package.
- 3) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see inner circuit).
- 4) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of completely eliminating parasitic effects.
- 5) Only the on/off conditions need to be set for operation, making the circuit design easy.
- 6) Lead Free/RoHS Compliant.

### Application

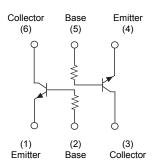
Inverter circuit, Interface circuit, Driver circuit

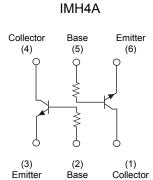
#### Outline



#### ●Inner circuit

### EMH4 / UMH4N





#### Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
EMH4	EMT6	1616	T2R	180	8	8,000	H4
UMH4N	UMT6	2021	TN	180	8	3,000	H4
IMH4A	SMT6	2928	T110	180	8	3,000	H4

## ● Absolute maximum ratings (Ta = 25°C)

<For Tr1 and Tr2 in common>

Paramete	er	Symbol	Values	Unit
Collector-base voltage		$V_{CBO}$	50	V
Collector-emitter voltage		$V_{CEO}$	50	V
Emitter-base voltage		$V_{EBO}$	5	V
Collector current		I <sub>C(MAX.)</sub> *1	100	mA
Collector Power dissipation EMH4 / UMH4N IMH4A		P <sub>D</sub> *2	150 (Total) <sup>*3</sup>	mW
		$P_{D}$	300 (Total) <sup>*4</sup>	mW
Junction temperature		T <sub>j</sub>	150	°C
Range of storage temperature		T <sub>stg</sub>	−55 to +150	°C

# ●Electrical characteristics(Ta = 25°C)

<For Tr1 and Tr2 in common>

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-base breakdown voltage	BV <sub>CBO</sub>	I <sub>C</sub> = 50μA	50	-	-	V
Collector-emitter breakdown voltage	BV <sub>CEO</sub>	I <sub>C</sub> = 1mA	50	-	-	V
Emitter-base breakdown voltage	BV <sub>EBO</sub>	I <sub>E</sub> = 50μA	5	-	-	V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = 50V	-	-	0.5	μА
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = 4V	1	1	0.5	μА
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> / I <sub>B</sub> = 10mA / 1mA	-	-	0.3	V
DC current gain	h <sub>FE</sub>	$V_{CE}$ = 5V , $I_{C}$ = 1mA ,	100	250	600	-
Input resistance	R <sub>1</sub>	-	7	10	13	kΩ
Transition frequency	f <sub>T</sub> *1	V <sub>CE</sub> = 10V, I <sub>E</sub> = -5mA, f = 100MHz	-	250	-	MHz

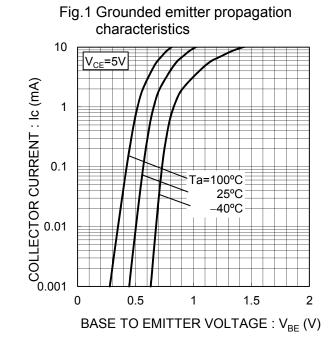
<sup>\*1</sup> Characteristics of built-in transistor

<sup>\*2</sup> Each terminal mounted on a reference footprint

<sup>\*3 120</sup>mW per element must not be exceeded.

<sup>\*4 200</sup>mW per element must not be exceeded.

### ●Electrical characteristic curves(Ta = 25°C)



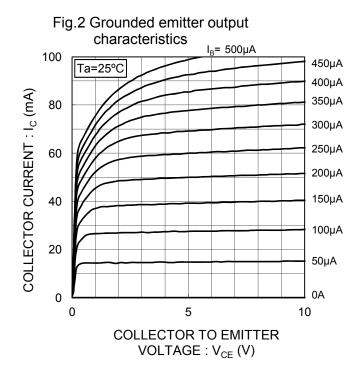
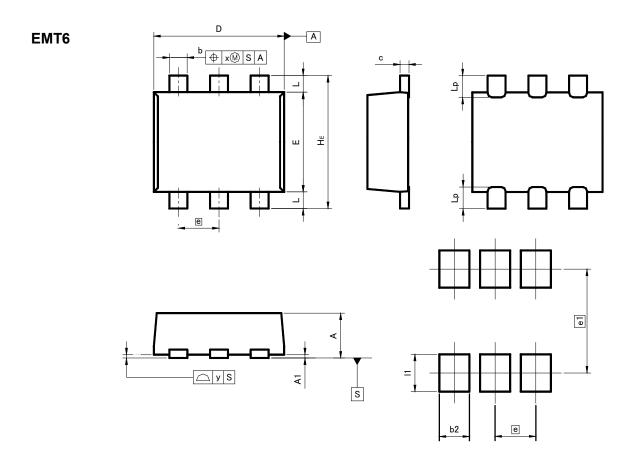


Fig.3 DC Current gain vs. Collector Current 1k V<sub>CE</sub>=5V 500 200 DC CURRENT GAIN: hFE Ta=100°C 100 25°C 50 -40°C 20 10 5 2 100μ 200μ 500μ 1m 2m 5m 10m 20m 50m100m COLLECTOR CURRENT : I<sub>C</sub> (mA)

Fig.4 Collector-emitter saturation voltage vs. Collector Current  $I_{\rm C}/I_{\rm B} = 10$ 500m 200m **COLLECTOR SATURATION** VOLTAGE: V<sub>CE</sub>(sat) (V) 100m Ta=100°C 25°C 50m 20m 10m 5m 2m 1m 100μ 200μ 500μ 1m 2m 5m 10m 20m 50m100m COLLECTOR CURRENT : I<sub>C</sub> (mA)

# ●Dimensions (Unit : mm)



## Patterm of terminal position areas

DIM	MILIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
A1	0.00	0.10	0	0.004
Α	0.45	0.55	0.018	0.022
b	0.17	0.27	0.007	0.011
С	0.08	0.18	0.003	0.007
D	1.50	1.70	0.059	0.067
E	1.10	1.30	0.043	0.051
е	0.	50	0.02	
HE	1.50	1.70	0.059	0.067
L	0.10	0.30	0.004	0.012
Lp	_	0.35	-	0.014
х	_	0.10		0.004
У	_	0.10	_	0.004

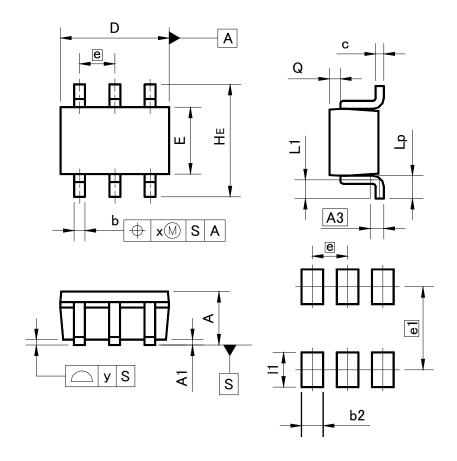
DIM	MILIMI	MILIMETERS		HES
MIN		MAX	MIN	MAX
e1	1.25		0.049	
b2	_	- 0.37		0.015
l1	_	0.45	_	0.018

Dimension in mm/inches

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# ●Dimensions (Unit : mm)

## UMT6



### Patterm of terminal position areas

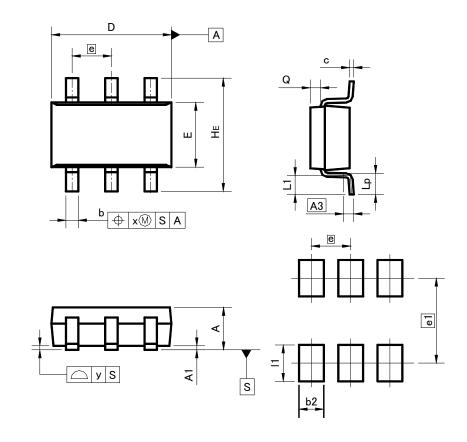
DIM MILIME		ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	0.80	1.00	ı	0.039
A1	0.00	0.10	0	0.004
A3	0.2	25	0.0	01
b	0.15	0.30	0.006	0.012
С	0.10	0.20	0.004	0.008
D	1.90	2.10	0.075	0.083
E	1.15	1.35	0.045	0.053
е	0.0	0.65		03
HE	2.00	2.20	0.079	0.087
L1	0.20	0.50	0.008	0.02
Lp	0.25	0.55	0.01	0.022
Q	0.10	0.30	0.004	0.012
х	_	0.10	- 1	0.004
у	_	0.10	_	0.004

DIM	MILIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
e1	1.55		0.06		
b2	- 0.40		ı	0.016	
l1	-	0.65	1	0.026	

Dimension in mm/inches

# ●Dimensions (Unit : mm)

## SMT6



## Patterm of terminal position areas

DIM	DIM MILIMETE		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	1.00	1.30	0.039	0.051
A1	0.00	0.10	0	0.004
A3	0.3	25	0.0	01
b	0.25	0.40	0.01	0.016
С	0.09	0.25	0.004	0.01
D	2.80	3.00	0.11	0.118
E	1.50	1.80	0.059	0.071
е	0.9	95	0.04	
HE	2.60	3.00	0.102	0.118
L1	0.30	0.60	0.012	0.024
Lp	0.40	0.70	0.016	0.028
Q	0.20	0.30	0.008	0.012
х	_	0.20		0.008
У	_	0.10	_	0.004

DIM	MILIMETERS		INCHES		
	MIN	MAX	MIN	MAX	
e1	2.10		0.08		
b2	0.60		_	0.024	
l1	-	0.90	1	0.035	

Dimension in mm/inches

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